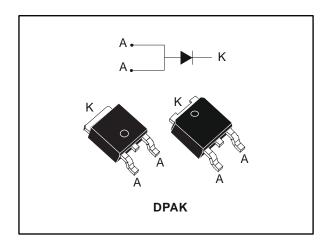
## **FERD2045S**



### 45 V field-effect rectifier diode

Datasheet - production data



#### **Features**

- ST advanced rectifier process
- Stable leakage current over reverse voltage
- Low forward voltage drop
- High frequency operation
- ECOPACK®2 compliant component for DPAK on demand

### **Description**

This single rectifier is based on a proprietary technology that achieves the best in class  $V_F/I_R$  trade-off for a given silicon surface.

Therefore it can advantageously replace 45 V low voltage Schottky diodes.

Packaged in DPAK, this device is intended to be used in rectification and freewheeling operations in power supplies.

**Table 1: Device summary** 

Symbol	Value
I <sub>F(AV)</sub>	20 A
V <sub>RRM</sub>	45 V
V <sub>F</sub> (typ.)	0.29 V
T <sub>i</sub> (max.)	150 °C

Characteristics FERD2045S

### 1 Characteristics

Table 2: Absolute ratings (limiting values at 25 °C, unless otherwise specified, anode terminals short-circuited)

Symbol	Parameter	Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse voltage	45	V	
I <sub>F(RMS)</sub>	Forward rms current	40	Α	
I <sub>F(AV)</sub>	Average forward current $\delta$ = 0.5, square wave $T_C = 125  ^{\circ}C$		20	Α
I <sub>FSM</sub>	Surge non repetitive forward current	180	Α	
T <sub>stg</sub>	Storage temperature range	-65 to +175	°C	
Tj	Maximum operating junction temperature	-40 to +150	°C	

#### Notes:

**Table 3: Thermal resistance parameters** 

Symbol	Parameter	Value	Unit
R <sub>th(j-c)</sub>	Junction to case	1.4	°C/W

Table 4: Static electrical characteristics (anode terminals short circuited)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
1 (1)	I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = 35 V	-	100	300	μΑ
		T <sub>j</sub> = 125 °C		-	12	24	mA
IR <sup>(*)</sup>		T <sub>j</sub> = 25 °C	V <sub>R</sub> = V <sub>RRM</sub>	-	200	600	μΑ
		T <sub>j</sub> = 125 °C		-	18	40	mΑ
V <sub>F</sub> <sup>(2)</sup>	Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 5 A	-	0.35		V
		T <sub>j</sub> = 125 °C		-	0.29		
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 10 A	-	0.41	0.45	
		T <sub>j</sub> = 125 °C		-	0.38	0.42	
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 20 A	-	0.51	0.55	
		T <sub>j</sub> = 125 °C		-	0.52	0.57	

#### Notes:

To evaluate the maximum conduction losses use the following equation:

$$P = 0.27 \text{ x } I_{F(AV)} + 0.015 \text{ x } I_{F^2(RMS)}$$

 $<sup>^{(1)}(</sup>dP_{tot}/dT_j) < (1/R_{th(j-a)})$  condition to avoid thermal runaway for a diode on its own heatsink.

 $<sup>^{(1)}\</sup>text{Pulse}$  test:  $t_p$  = 5 ms,  $\delta$  < 2%

 $<sup>^{(2)}</sup>$ Pulse test:  $t_p$  = 380  $\mu$ s,  $\delta$  < 2%

FERD2045S Characteristics

### 1.1 Characteristics (curves)

Figure 1: Average forward current versus ambient temperature ( $\delta = 0.5$ )

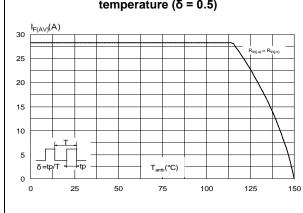


Figure 2: Relative variation of thermal impedance junction to case versus pulse duration  $Z_{th(j-c)}/R_{th(j-c)}$ 1.0 0.9 0.8 0.7 0.6 0.5 0.4 0.3 0.2 0.1 t<sub>p</sub>(s) 0.0 1.E-04 1.E-03 1.E-02 1.E+00 1.E-01

Figure 3: Reverse leakage current versus reverse voltage applied (typical values)

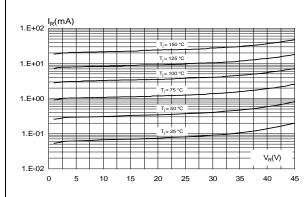


Figure 4: Junction capacitance versus reverse voltage applied (typical values)

C(pF)

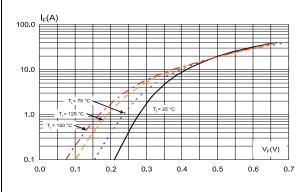
10000

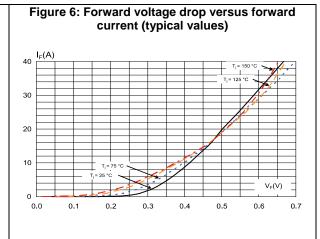
V<sub>R</sub>(V)

100

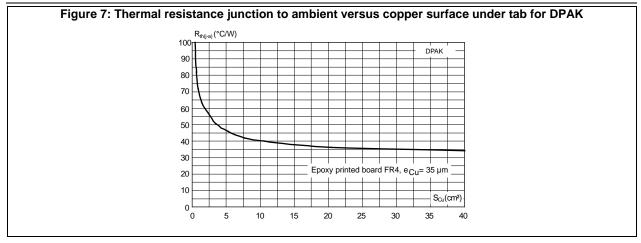
1 100 100

Figure 5: Forward voltage drop versus forward current (typical values)





Characteristics FERD2045S



FERD2045S Package information

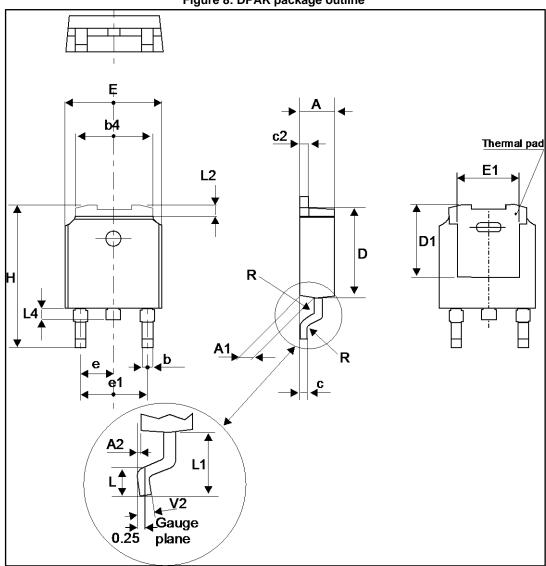
## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

- Cooling method: by conduction (C)
- Epoxy meets UL 94,V0

### 2.1 DPAK package information

Figure 8: DPAK package outline



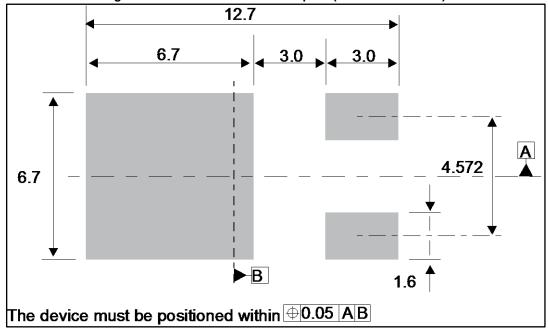


This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 5: DPAK package mechanical data

	Dimensions					
Ref.	Millimeters		Inches			
	Min.	Max.	Min.	Max.		
А	2.18	2.40	0.085	0.094		
A1	0.90	1.10	0.035	0.043		
A2	0.03	0.23	0.001	0.009		
b	0.64	0.90	0.025	0.035		
b4	4.95	5.46	0.194	0.215		
С	0.46	0.61	0.018	0.024		
c2	0.46	0.60	0.018	0.023		
D	5.97	6.22	0.235	0.244		
D1	4.95	5.60	0.194	0.220		
Е	6.35	6.73	0.250	0.265		
E1	4.32	5.50	0.170	0.216		
е	2.286 typ.		0.090	) typ.		
e1	4.40	4.70	0.173	0.185		
Н	9.35	10.40	0.368	0.409		
L	1.0	1.78	0.039	0.070		
L2		1.27		0.050		
L4	0.60	1.02	0.023	0.040		
V2	-8°	+8°	-8°	+8°		

Figure 9: DPAK recommended footprint (dimensions in mm)



FERD2045S Ordering information

# 3 Ordering information

**Table 6: Ordering information** 

Order code	Marking	Package	Weight	Base qty.	Delivery mode
FERD2045SB-TR	FERD 2045	DPAK	0.32 g	2500	Tape and reel

# 4 Revision history

Table 7: Document revision history

Date	Revision	Changes
15-Jan-2018	1	Initial release.

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